

Technical Data Data Sheet N1192, Rev. B Green Products

208CNQ060 SCHOTTKY RECTIFIER

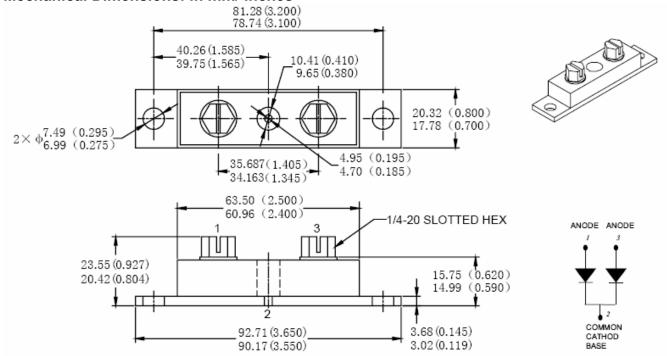
Applications:

- High current switching power supply Plating power supply Free-Wheeling diodes
- Reverse battery protection Converters UPS System Welding

Features:

- 150°C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/ Inches



PRM4 (Non-Isolated)

MARKING, MOLDING RESIN

Marking for 208CNQ060, 1st row SS YYWWL, 2nd row 208CNQ060 Where YY is the manufacture year WW is the manufacture week code L is the wafer's Lot Number Molding resin

Epoxy resin UL:94V-0

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Technical Data Data Sheet N1192, Rev. B **Maximum Ratings:**

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Characteristics	Symbol	Condition	Max.		Un	nits
Peak Inverse Voltage	V_{RWM}	-	60		,	V
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =90°C,	100 per leg		-	Α
		rectangular wave form	200	per device		
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	2520		,	Α
Non-Repetitive Avalanche Energy(peg leg)	E _{AS}	T_J =25 $^{\circ}$ C, I_{AS} =1A,L=30mH	15		n	nJ
Repetitive Avalanche Current(peg leg)	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A =1.5× V_R typical		1	,	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units	
Max. Forward Voltage Drop (per leg) *	V _{F1}	@ 100A, Pulse, T _J = 25 °C	0.68	V	
		@ 200A, Pulse, T _J = 25 °C	0.83	V	
	\/	@ 100A, Pulse, T _J = 125 °C	0.59	V	
	V_{F2}	@ 200A, Pulse, T _J = 125 °C	0.75	V	
Max. Reverse Current (per	I _{R1}	$@V_R = \text{rated } V_R T_J = 25 ^{\circ}\text{C}$	1.1	mA	
leg) *	I _{R2}	$@V_R = \text{rated } V_R T_J = 125 ^{\circ}\text{C}$	300	mA	
Max. Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C	6000	Pf	
(per leg)	01	$f_{SIG} = 1MHz$	333		
Typical Series Inductance	1.	Measured lead to lead 5 mm	7.0	Nh	
(per leg)	L _S	from package body	7.0	INII	
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs	
Insulation Voltage	V_{RMS}	-	1000	V	

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specifi	Units		
Max. Junction Temperature	T_J	-	-55 to	°C		
Max. Storage Temperature	T _{stg}	-	-55 to	°C		
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ heta JC}$	DC operation	0.5	°C/W		
Maximum Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.25		°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.1	°C/W		
Mounting Torque	Тм	-	Mounting Torque Terminal Torque	24(min) 35(max) 35(min) 46(max)	Kg-cm	
Approximate Weight	wt	-	79		g	
Case Style	PRM4 Non-Isolated					

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10⁻¹

0.0

0.2

0.4

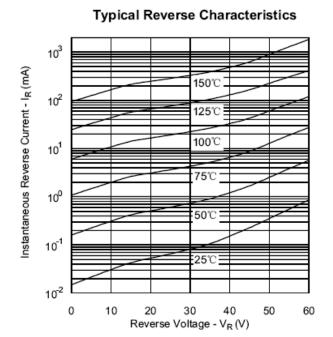
Forward Voltage Drop - V_F(V)

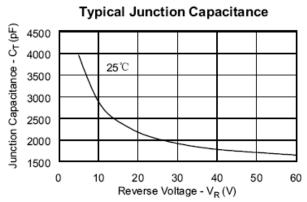
0.6

8.0

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Typical Forward Characteristics 10² 150°C 150°C 125°C 25°C





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208CNQ060

Technical Data
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Green Products

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